



Fast Recovery Diode

Replaces March 1998 version, DS4210-2.2

DS4210-3.0 January 2000

KEY PARAMETERS

APPLICATIONS

- Induction Heating
- A.C. Motor Drives
- Snubber Diode
- Welding
- High Frequency Rectification
- **■** UPS

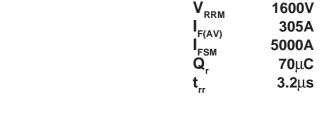
FEATURES

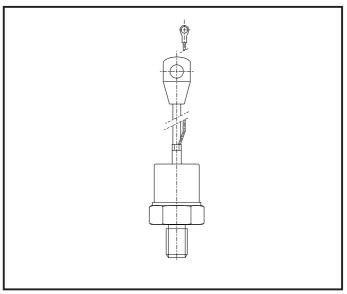
- Thermal Fatigue Free Pressure Contact
- High Surge Capability
- Low Recovery Charge

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V	Conditions
TV22 16F M or K	1600	$V_{RSM} = V_{RRM} + 100V$
TV22 14F M or K	1400	KOW KKW
TV22 12F M or K	1200	
TV22 10F M or K	1000	
TV22 08F M or K	800	
TV22 06F M or K	600	

For 3/4" 16 UNF thread, add suffix K, e.g. TV22 16FK. For M16 thread, add suffix M, e.g. TV22 16FM. For stud anode add 'R' to type number, e.g. TV22 16FMR.





Outline type codes: DO9.
See Package Details for further information.

CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{F(AV)}	Mean forward current	Half wave resistive load, T _{case} = 65°C	305	А
I _{F(RMS)}	RMS value	$T_{case} = 65^{\circ}C$	346	А

TV22..F

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine: with 09/ V	5.0	kA
l ² t	I ² t for fusing	10ms half sine; with 0% V _{RRM,} T _j = 150°C	125 x 10 ³	A ² s
I _{FSM}	Surge (non-repetitive) forward current	10mg half ging; with 50% \ \ T = 150°C	-	kA
l ² t	I ² t for fusing	10ms half sine; with 50% V_{RRM} , $T_j = 150$ °C	-	A²s

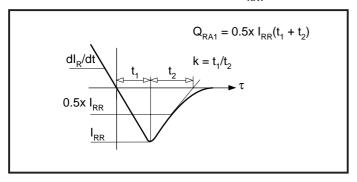
THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance - junction to case	dc	-	0.16	°C/W
R _{th(c-h)}	Thermal resistance - case to heatsink	Mounting torque 35.0Nm with mounting compound	-	0.06	°C/W
T _{vj}	Virtual junction temperature	On-state (conducting)	-	150	°C
T _{stg}	Storage temperature range		-55	175	°C
-	Mounting torque		30.0	35.0	Nm

CHARACTERISTICS

Symbol	Parameter	Conditions	Тур.	Max.	Units
V _{FM}	Forward voltage	At 750A peak, T _{case} = 25°C	-	1.6	٧
I _{RRM}	Peak reverse current	At V _{RRM} , T _{case} = 150°C	-	40	mA
t _{rr}	Reverse recovery time		-	3.2	μs
Q _{RA1}	Recovered charge (50% chord)	$I_{\rm F} = 750$ A, $di_{\rm RR}/dt = 100$ A/ μ s	-	70	μС
I _{RM}	Reverse recovery current	$T_{case} = 125^{\circ}C, V_{R} = 100V$	-	43	А
К	Soft factor		1.8	-	-
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	1.0	٧
r _T	Slope resistance	At T _{vj} = 150°C	-	0.8	mΩ
$V_{\sf FRM}$	Forward recovery voltage	di/dt = 1000A/μs, T _j = 125°C	-	-	V

DEFINITION OF K FACTOR AND $\boldsymbol{Q}_{\text{RA1}}$



CURVES

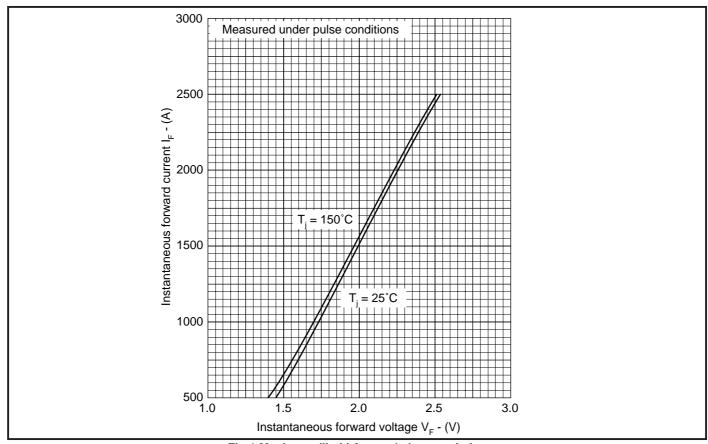


Fig.1 Maximum (limit) forward characteristics

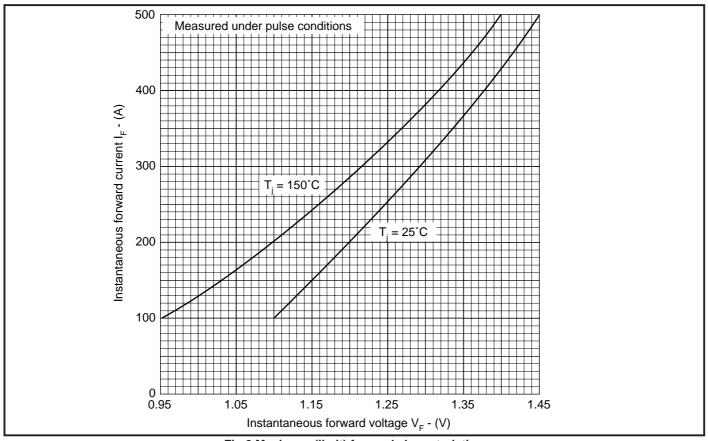


Fig.2 Maximum (limit) forward characteristics

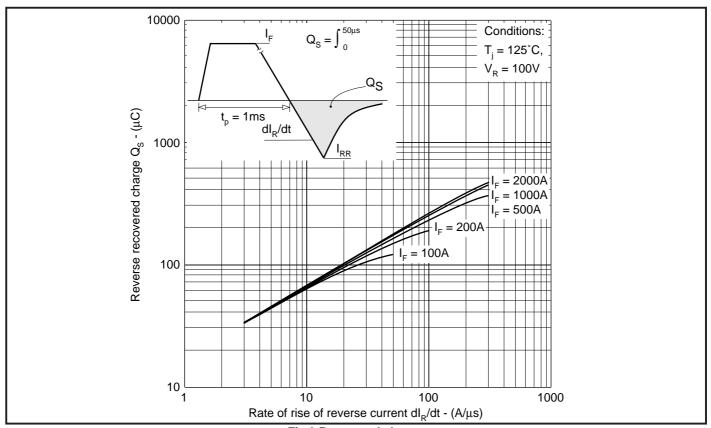


Fig.3 Recovered charge

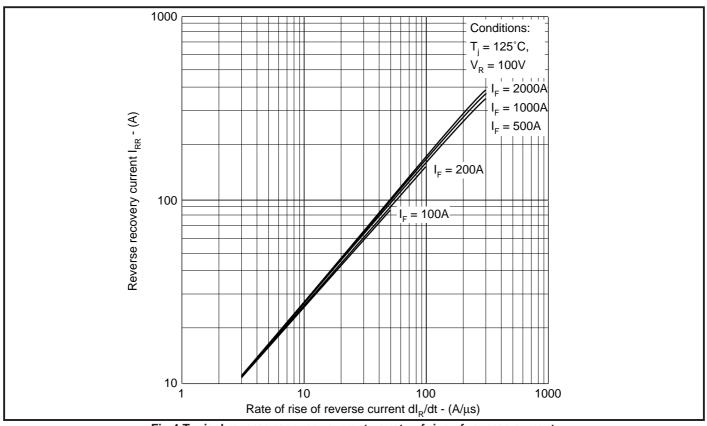


Fig.4 Typical reverse recovery current vs rate of rise of reverse current

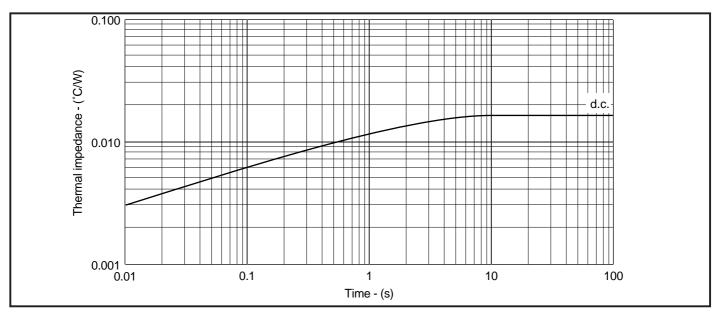
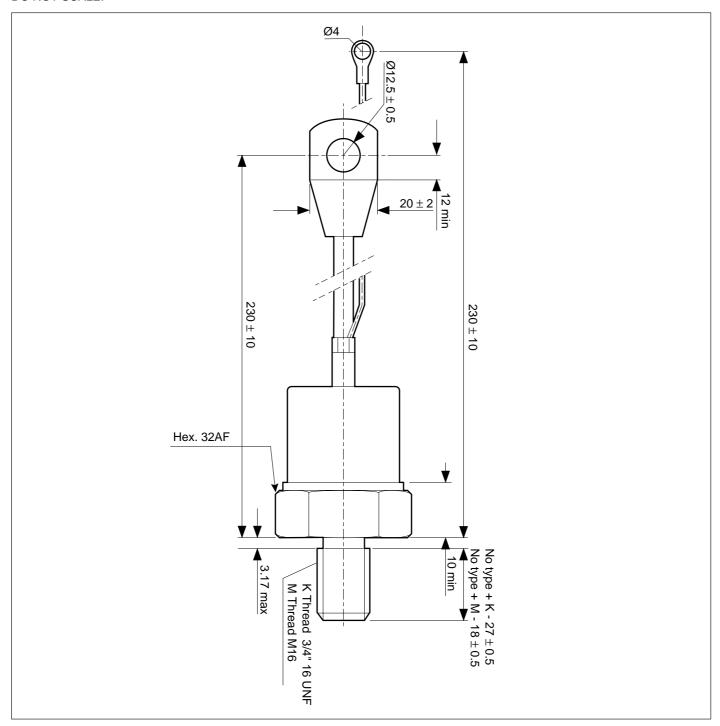


Fig.5 Maximum (limit) transient thermal impedance - junction to case - (°C/W)

TV22..F

PACKAGE DETAILS

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



ASSOCIATED PUBLICATIONS

Title	Application Note	
	Number	
Calculating the junction temperature or power semiconductors	AN4506	
Thyristor and diode measurement with a multi-meter	AN4853	
Use of V _{TO} , r _T on-state characteristic	AN5001	

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We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

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For further information on device clamps, heatsinks and assemblies, please contact your nearest Sales Representative or the factory.



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